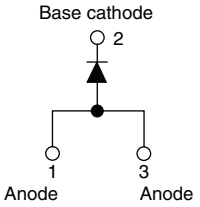
Input Rectifier Diode, 20 A

D²PAK



DESCRIPTION/FEATURES

The 20ETS...SPbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

Pb Available

RoHS* COMPLIANT

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

This product has been designed and qualified for industrial level and lead (Pb)-free.

PRODUCT SUMMARY	
V_F at 10 A	1 V
I_{FSM}	300 A
V_{RRM}	800/1200 V

OUTPUT CURRENT IN TYPICAL APPLICATIONS			
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS
Capacitive input filter T_A = 55 °C, T_J = 125 °C common heatsink of 1 °C/W	16.3	21	A

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	20	A
V_{RRM}		800/1200	V
I_{FSM}		300	A
V_F	20 A, T_J = 25 °C	1.1	V
T_J		- 40 to 150	°C

VOLTAGE RATINGS			
PART NUMBER	V_{RRM}, MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM}, MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
20ETS08SPbF	800	900	1
20ETS12SPbF	1200	1300	

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	T_C = 105 °C, 180° conduction half sine wave	20	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	250	A
		10 ms sine pulse, no voltage reapplied	300	A
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	316	A^2s
		10 ms sine pulse, no voltage reapplied	442	A^2s
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reapplied	4420	$A^2\sqrt{s}$

* Pb containing terminations are not RoHS compliant, exemptions may apply

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V_{FM}	20 A, T_J = 25 °C		1.1	V
Forward slope resistance	r_t	T_J = 150 °C		10.4	mΩ
Threshold voltage	$V_{F(TO)}$			0.85	V
Maximum reverse leakage current	I_{RM}	T_J = 25 °C	V_R = Rated V_{RRM}	0.1	mA
		T_J = 150 °C		1.0	

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.3	°C/W
Maximum thermal resistance, junction to ambient		R_{thJA} (1)	For D^2PAK version	62	
Typical thermal resistance, case to heatsink		R_{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6.0 (5.0)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style D^2PAK (SMD-220)	20ETS08S	
				20ETS12S	

Note

(1) When mounted on 1" square (650 mm^2) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W
For recommended footprint and soldering techniques refer to application note #AN-994

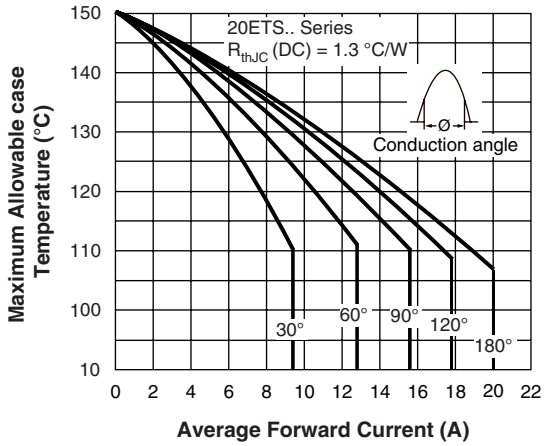


Fig. 1 - Current Rating Characteristics

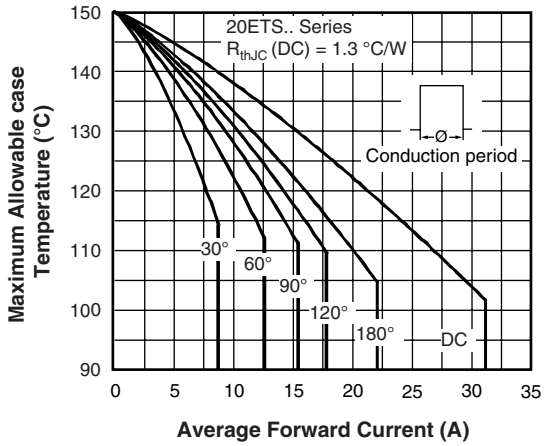


Fig. 2 - Current Rating Characteristics

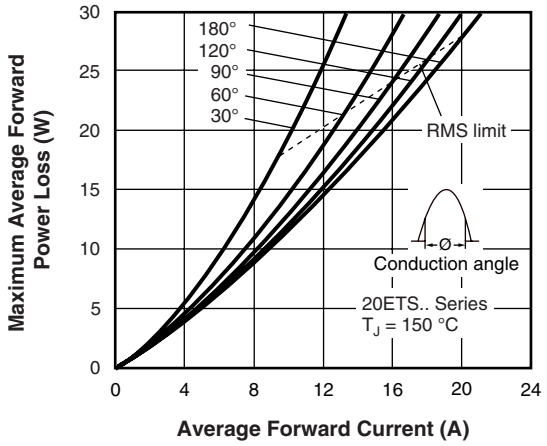


Fig. 3 - Forward Power Loss Characteristics

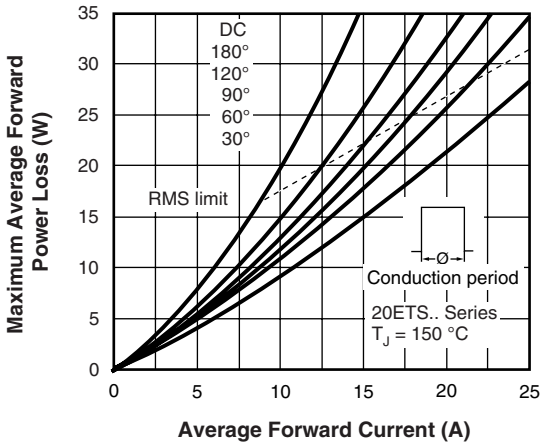


Fig. 4 - Forward Power Loss Characteristics

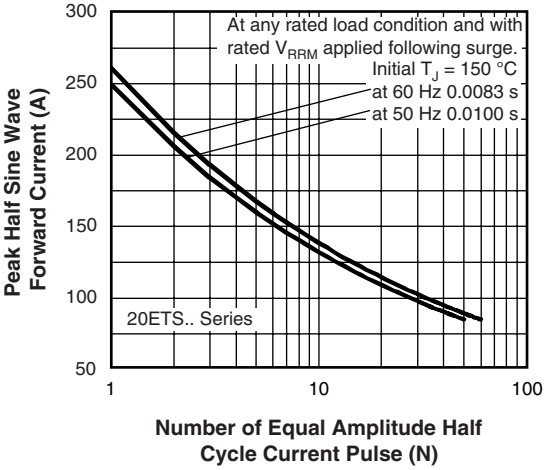


Fig. 5 - Maximum Non-Repetitive Surge Current

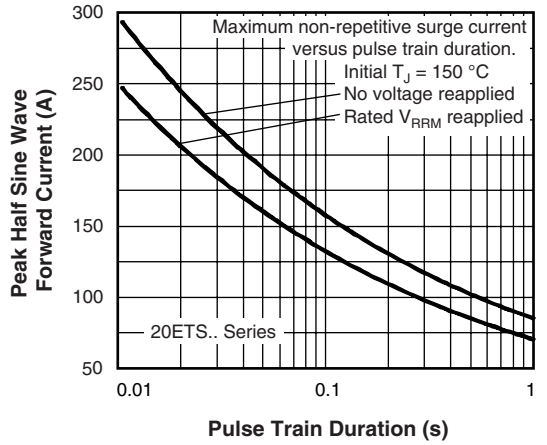


Fig. 6 - Maximum Non-Repetitive Surge Current

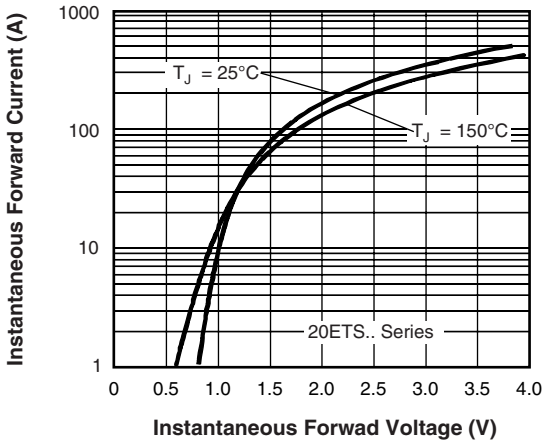


Fig. 7 - Forward Voltage Drop Characteristics

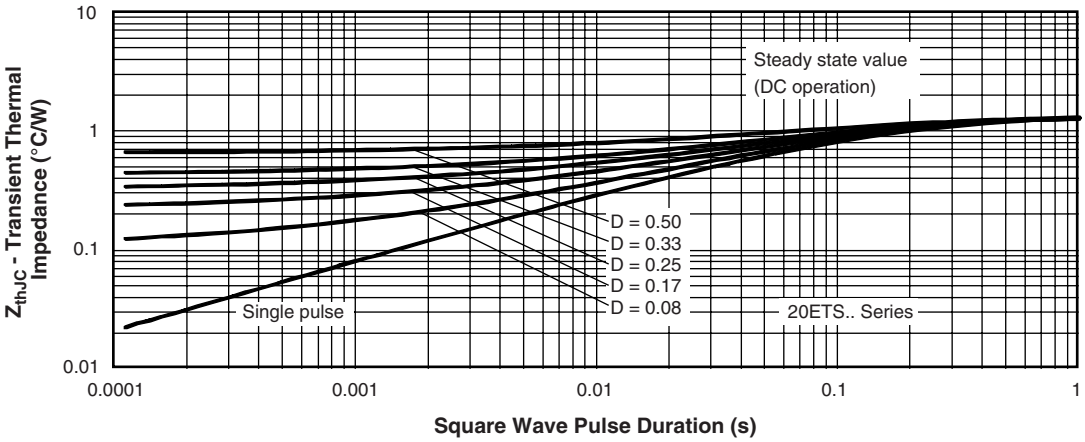


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	20	E	T	S	12	S	TRL	PbF
	1	2	3	4	5	6	7	8

1 - Current rating (20 = 20 A)

2 - Circuit configuration
E = Single diode

3 - Package:
T = TO-220AC

4 - Type of silicon:
S = Standard recovery rectifier

5 - Voltage code x 100 = V_{RRM} — 08 = 800 V, 12 = 1200 V

6 - S = TO-220 D^2PAK (SMD-220) version

7 - • None = Tube
• TRL = Tape and reel (left oriented)
• TRR = Tape and reel (right oriented)

8 - • None = Standard production
• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95046
Part marking information	http://www.vishay.com/doc?95054
Packaging information	http://www.vishay.com/doc?95032

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